Reg. No.					



SEVENTH SEMESTER B.Tech. (E & C) DEGREE END SEMESTER EXAMINATION NOV 2017

SUBJECT: MICROWAVE INTEGRATED CIRCUITS (ECE - 441)

TIME: 3 HOURS MAX. MARKS: 50

Instructions to candidates

- Answer **ANY FIVE** questions.
- Missing data may be suitably assumed.
- 1A. Design a rectangular microstrip antenna using a substrate with dielectric constant $\varepsilon_r = 3.2$, substrate height h = 1.6cm, so as to resonant at 1.5GHz, and compare the Physical and effective length of patch antenna.
- 1B. What is Isolator? What are the applications of it? How the modes of waves are changes in it?
- 1C. What is gyromagnetic resonance? and explain its resonance frequency.

(5+3+2)

- 2A. Design a three pole microstrip low pass filter in chebyshev response for the given parameters , dielectric Constant $\varepsilon_r = 10.2$, substrate height h = 1.27mm, cut off frequency $f_c = 1GHz$. the prototype constant for a pass band ripple =0.1db are $g_0 = g_4 = 1$, $g_1 = g_3 = 1.0000$, $g_2 = 2.000$.
- 2B. How the frequencies are up and down converted in the microwave mixer? Explain mathematically.
- 2C. A transmission line has the following parameters: R=2 ohm/m, G=0.5 mili mho/m, f=1GHz, L=8 nH/m, C=0.23pf, Calculate (a) the characteristics Impedance; (b) the propagation constant.

(5+3+2)

- 3A. Explain the fabrication, V-I characteristics and its different mode of switching configuration of PIN Diode.
- 3B. What is frequency multiplier? Explain diode frequency multiplier.
- 3C. For a certain transmission line, the return loss for a load is observed to be equal to 18 dB. Calculate the reflection coefficient and SWR

(5+3+2)

4A. Design a microstrip high pass filter by using ditributed short circuited stubs for the given parameters n=4, $f_c=1.5GHz$, $\varepsilon_r=2.2$, h=1.57mm, the admittances are $y_1=0.32300$, $y_{1,2}=1.07842$, $y_2=0.39443$, $y_{2,3}=1.06488$.

- 4B. Write three relative advantages and Disadvantages of MMIC over hybrid MIC
- 4C. What are types of coupler? Explain its even and odd mode analysis.

(5+3+2)

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- 5A. Explain the fabrication Method of Schottky Barrier Diode (SBD) and working principle of SBD.
- 5B. Explain with diagram
 - i) Reciprocal and Non Reciprocal Phase Shifters.
 - ii) Electrical length of Microstrip
- 5C. Explain the following: (a) Image frequency (b) Conversion Loss

(5+3+2)

- 6A. Determine the characteristics impedance and the effective dielectric constants for a microstrip transmission line fabricated in an alumina substrate ($e_r = 9.7$) if the ratio w/h is (i) 0.5 (ii) 5. Also find the velocity of propagation in each case.
- 6B. What are types of losses in transmission line? Explain any three, with mathematical equations.
- 6C. Explain (a) Critical coupling (b) Aperture coupled cavity

(5+3+2)

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